



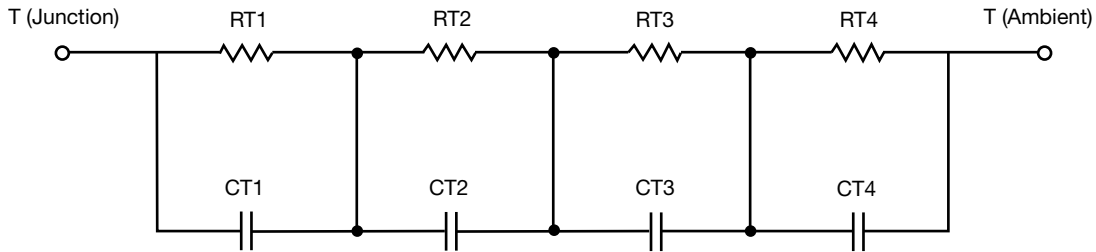
R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	81.2980	N/A	N/A
RT2	172.0427	N/A	N/A
RT3	191.9208	N/A	N/A
RT4	53.9364	N/A	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	343.5674u	N/A	N/A
CT2	3.8256m	N/A	N/A
CT3	9.5779m	N/A	N/A
CT4	889.2507m	N/A	N/A

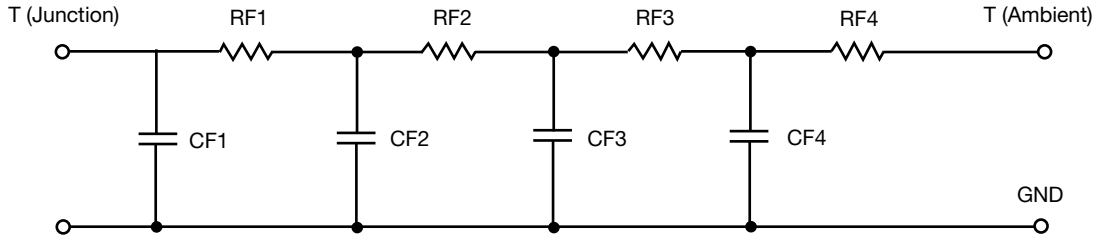
Note

- n/a indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



R-C THERMAL MODEL FOR FILTER CONFIGURATION



R-C VALUES FOR FILTER CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RF1	109.6506	N/A	N/A
RF2	307.0070	N/A	N/A
RF3	58.3411	N/A	N/A
RF4	27.5156	N/A	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	333.2893u	N/A	N/A
CF2	2.8059m	N/A	N/A
CF3	134.7270m	N/A	N/A
CF4	4.4898	N/A	N/A

Note

- n/a indicates not applicable

